

Electrical Characteristics @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Min	Max	Unit	Test Condition			
OFF CHARACTERISTICS (Note 4)								
Collector-Base Breakdown Voltage	V _{(BR)CBO}	-40	_	V	$I_C = -10\mu A, I_E = 0$			
Collector-Emitter Breakdown Voltage	V _{(BR)CEO}	-40	_	V	$I_C = -1.0 \text{mA}, I_B = 0$			
Emitter-Base Breakdown Voltage	V _{(BR)EBO}	-5.0	_	V	$I_E = -10\mu A, I_C = 0$			
Collector Cutoff Current	I _{CEX}	_	-50	nA	$V_{CE} = -30V, V_{EB(OFF)} = -3.0V$			
	I _{CBO}		-50	nA	$V_{CB} = -30V, I_{E} = 0$			
Base Cutoff Current	I _{BL}		-50	nA	$V_{CE} = -30V, V_{EB(OFF)} = -3.0V$			
ON CHARACTERISTICS (Note 4)								
DC Current Gain	h _{FE}	60 80 100 60 30	 300 	_	$\begin{split} I_{C} &= -100 \mu A, \ V_{CE} = -1.0 V \\ I_{C} &= -1.0 m A, \ V_{CE} = -1.0 V \\ I_{C} &= -10 m A, \ V_{CE} = -1.0 V \\ I_{C} &= -50 m A, \ V_{CE} = -1.0 V \\ I_{C} &= -100 m A, \ V_{CE} = -1.0 V \end{split}$			
Collector-Emitter Saturation Voltage	V _{CE(SAT)}	_	-0.25 -0.40	V	$I_C = -10$ mA, $I_B = -1.0$ mA $I_C = -50$ mA, $I_B = -5.0$ mA			
Base-Emitter Saturation Voltage	V _{BE(SAT)}	-0.65 —	-0.85 -0.95	V	$I_C = -10$ mA, $I_B = -1.0$ mA $I_C = -50$ mA, $I_B = -5.0$ mA			
SMALL SIGNAL CHARACTERISTICS					_			
Output Capacitance	C_{obo}	_	4.5	pF	$V_{CB} = -5.0V$, $f = 1.0MHz$, $I_E = 0$			
Input Capacitance	C _{ibo}	_	10	pF	$V_{EB} = -0.5V$, $f = 1.0MHz$, $I_{C} = 0$			
Input Impedance	h _{ie}	2.0	12	kΩ	V _{CE} = -10V, I _C = -1.0mA, f = 1.0kHz			
Voltage Feedback Ratio	h _{re}	0.1	10	x 10 ⁻⁴				
Small Signal Current Gain	h _{fe}	100	400	_				
Output Admittance	h _{oe}	3.0	60	μS				
Current Gain-Bandwidth Product	f _T	250		MHz	$V_{CE} = -20V, I_{C} = -10mA, f = 100MHz$			
Noise Figure	NF	_	4.0	dB	V_{CE} = -5.0V, I_{C} = -100 μ A, R_{S} = 1.0k Ω , f = 1.0kHz			
SWITCHING CHARACTERISTICS								
Delay Time	t _d	_	35	ns	$V_{CC} = -3.0V, I_{C} = -10mA,$			
Rise Time	t _r	_	35	ns	$V_{BE(off)} = 0.5V, I_{B1} = -1.0mA$			
Storage Time	ts	_	225	ns	$V_{CC} = -3.0V, I_{C} = -10mA,$			
Fall Time	t _f		75	ns	$I_{B1} = I_{B2} = -1.0 \text{mA}$			

4. Measured under pulsed condition. Pulse width = 300μs. Duty cycle ≤2%. Notes:

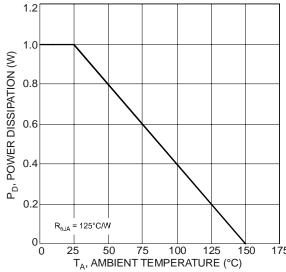
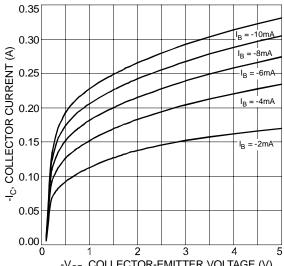
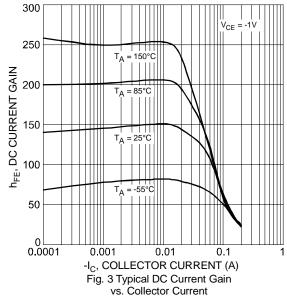


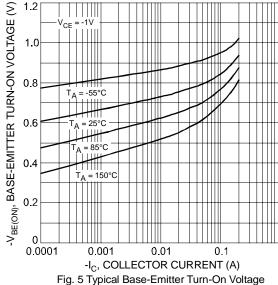
Fig. 1 Power Dissipation vs. Ambient Temperature (Note 3)

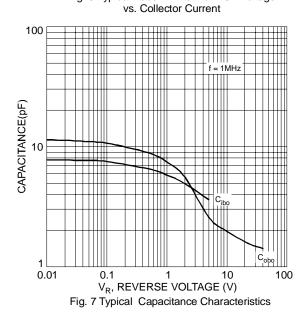


 $\hbox{-V}_{\text{CE}}, \hbox{COLLECTOR-EMITTER VOLTAGE (V)} \\ \hbox{Fig. 2 Typical Collector Current vs.Collector-Emitter Voltage} \\$









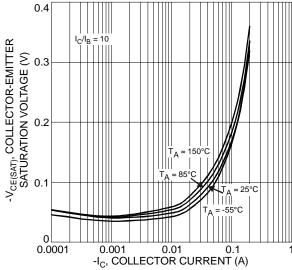


Fig. 4 Typical Collector-Emitter Saturation Voltage vs. Collector Current

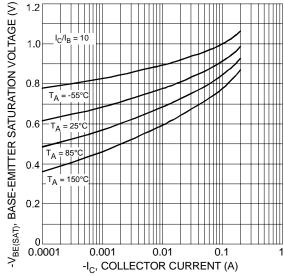


Fig. 6 Typical Base-Emitter Saturation Voltage vs. Collector Current

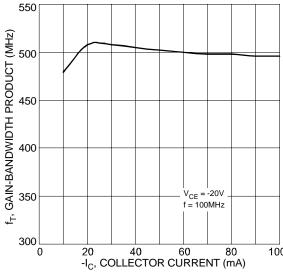


Fig. 8 Typical Gain-Bandwidth Product vs. Collector Current

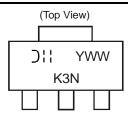


Ordering Information (Note 5)

Device	Packaging	Shipping
DXT3906-13	SOT89-3L	2500/Tape & Reel

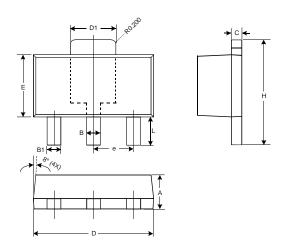
Notes: 5. For packaging details, go to our website at http://www.diodes.com/ap02007.pdf.

Marking Information



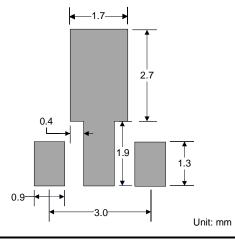
K3N = Product Type Marking Code
Office Manufacturer's Marking Code
YWW = Date Code Marking
Y = Last digit of year ex: 7 = 2007
WW = Week code 01 - 52

Package Outline Dimensions



SOT89-3L							
Dim	Min	Max	Тур				
Α	1.40	1.60	1.50				
В	0.45	0.55	0.50				
B1	0.37	0.47	0.42				
С	0.35	0.43	0.38				
D	4.40	4.60	4.50				
D1	1.50	1.70	1.60				
Е	2.40	2.60	2.50				
е		1	1.50				
Н	3.95	4.25	4.10				
L	0.90	1.20	1.05				
All Dimensions in mm							

Suggested Pad Layout



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